# NSN 5961-00-359-6812

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| Inclosure Material |   |
|--------------------|---|
| inciosure material | : |

Metal

**Overall Length:** 

0.260 inches

### Terminal Length:

1.500 inches

#### **Overall Diameter:**

0.370 inches

#### Internal Configuration:

Junction contact

- Joint Electronic Device Engineering Council/jedec/case Outline Designation:
- To-5

#### **Mounting Method:**

Terminal

#### Terminal Circle Diameter:

0.200 inches

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

4.0 emitter to base voltage, static, collector open and 40.0 collector to base voltage/static/emitter open and 30.0 collector to emitter voltage/static/base open

#### **Current Rating Per Characteristic:**

600.00 milliamperes source cutoff current

#### **Power Rating Per Characteristic:**

3.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: pnp

# **Precious Material And Location:**

Terminal surfaces gold

# **Precious Material:**

Gold

# Terminal Type And Quantity:

3 uninsulated wire lead

# Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

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